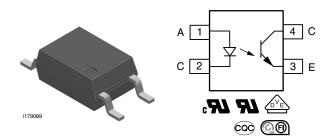


Low Input Current, Phototransistor Output, SOP-4, Mini-Flat Package



DESCRIPTION

The 110 °C rated VOM617A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin 100 mil lead pitch miniflat package. It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

These coupling devices are designed for signal transmission between two electrically separated circuits.

AGENCY APPROVALS

(All parts are certified under base model VOM617A)

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065 and EN 60950-1
- CQC GB8898-2011, GB4943.1-2001

FEATURES

- Operating temperature from 55 °C to + 110 °C
- SOP-4 mini-flat package
- Isolation test voltage, 3750 V_{RMS}
- Low saturation voltage
- · Fast switching times
- · Low coupling capacitance
- End-stackable, 0.100" (2.54 mm) spacing
- CTR range 40 % to 600 %, I_F = 5 mA
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT

APPLICATIONS

- PLCs
- Telecommunication
- · Lighting control system
- Solar inverters
- AC drives

ORDERING INFORMATION									
V O M 6 1 7 A - # X O O 1 T PART NUMBER CTR VDE OPTION TAPE AND REEL SOP-4									
AGENCY CERTIFIED/	CTR (%)								
PACKAGE									
UL, cUL, FIMKO, CQC	50 to 600 63 to 125 100 to 200 160 to 320 250 to 500 80 to 160 130 to 260 200 to 4						200 to 400		
SOP-4, mini-flat	VOM617AT VOM617A-2T VOM617A-3T VOM617A-4T VOM617A-6T VOM617A-7T VOM617A-8T VOM617A-9T								
VDE, UL, cUL, FIMKO, CQC	50 to 600 63 to 125 100 to 200 160 to 320 250 to 500 80 to 160 130 to 260 200 to 400								
SOP-4, mini-flat	VOM617A- X001T	VOM617A- 2X001T	VOM617A- 3X001T	VOM617A- 4X001T	VOM617A- 6X001T	VOM617A- 7X001T	VOM617A- 8X001T	VOM617A- 9X001T	



ABSOLUTE MAXIMUM RAT	INGS (T _{amb} = 25 °C, unless	otherwise spe	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT	·			
DC forward current		I _F	60	mA
Reverse voltage		V _R	6	V
Power dissipation		P _{diss}	70	mW
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	А
OUTPUT	·			
Collector emitter voltage		V _{CEO}	80	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		,	50	mA
Collector current	t _p ≤ 1 ms	l _C	100	mA
Power dissipation		P _{diss}	150	mW
COUPLER	·			
Isolation test voltage between emitter and detector	t = 1 min	V _{ISO}	3750	V _{RMS}
Total power dissipation		P _{tot}	170	mW
Operating temperature range		T _{amb}	- 55 to + 110	°C
Storage temperature range		T _{stg}	- 55 to + 150	°C
Junction temperature		T _j	125	°C
Soldering temperature (1)		T _{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) See "Assembly Instructions" for surface mounted devices (www.vishay.com/doc?80054).

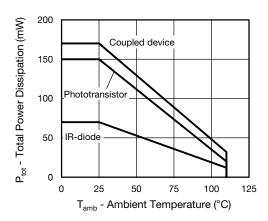


Fig. 1 - Total Power Dissipation vs. Ambient Temperature



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
Forward voltage	$I_F = 5 \text{ mA}$	V _F		1.1	1.6	V			
Reverse current	V _R = 6 V	I _R		0.01	10	μA			
Capacitance	V _R = 0 V, f = 1 MHz	Cj		9		pF			
OUTPUT									
Collector emitter leakage current	V _{CE} = 20 V	I _{CEO}		0.3	100	nA			
Collector emitter breakdown voltage	$I_C = 100 \mu A$	BV _{CEO}	80			V			
Emitter collector breakdown voltage	I _E = 10 μA	BV _{ECO}	7			V			
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}		2.8		pF			
COUPLER									
Coupling capacitance	f = 1 MHz	C _{IO}		0.3		pF			
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$	V _{CEsat}		0.12	0.4	V			
Cut-off frequency	$I_F = 10$ mA, $V_{CC} = 5$ V, $R_L = 100$ Ω	f _{ctr}		110		kHz			

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
l _C /l _F		VOM617A	CTR	50		600	%	
		VOM617A-2	CTR	63		125	%	
		VOM617A-3	CTR	100		200	%	
	1 - 5 m	VOM617A-4	CTR	160		320	%	
	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	VOM617A-6	CTR	250		500	%	
		VOM617A-7	CTR	80		160	%	
		VOM617A-8	CTR	130		260	%	
		VOM617A-9	CTR	200		400	%	

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
NON-SATURATED								
Rise and fall time		t _r		3		μs		
Fall time	$I_{C} = 2 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f		3		μs		
Turn-on time	$R_L = 100 \Omega$	t _{on}		6		μs		
Turn-off time		t _{off}		4		μs		
SATURATED								
Rise and fall time		t _r		7		μs		
Fall time	$I_F = 1.6 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f		12		μs		
Turn-on time	$R_L = 1.9 \text{ k}\Omega$	t _{on}		9		μs		
Turn-off time		t _{off}		15		μs		



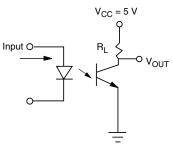


Fig. 2 - Test Circuit

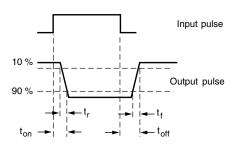


Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION	I RATINGS			
PARAMETER		SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS				
Output safety power		P _{SO}	300	mW
Input safety current		I _{si}	200	mW
Safety temperature		T _S	150	°C
Comparative tracking index		CTI	175	
INSULATION RATED PARAMETER	s			
Maximum withstanding isolation volta	V _{ISO}	3750	V _{RMS}	
Maximum transient isolation voltage		V _{IOTM}	6000	V_{peak}
Maximum repetitive peak isolation vo	oltage	V _{IORM}	565	V _{peak}
Insulation resistance	$T_{amb} = 25 ^{\circ}C, V_{DC} = 500 V$	R _{IO}	10 ¹²	Ω
Isolation resistance	$T_{amb} = 100 ^{\circ}\text{C}, V_{DC} = 500 \text{V}$	R _{IO}	10 ¹¹	Ω
Climatic classification (according to I	EC 68 part 1)		55/110/21	
Environment (pollution degree in acco	ordance to DIN VDE 0109)		2	
Internal creepage		≥ 5	mm	
External creepage			≥ 5	mm
Clearance			≥ 5	mm
Insulation thickness			≥ 0.4	mm

Note

• As per DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

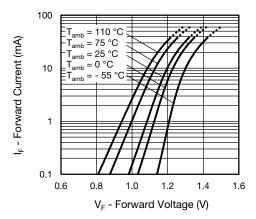


Fig. 4 - Forward Voltage vs. Forward Current

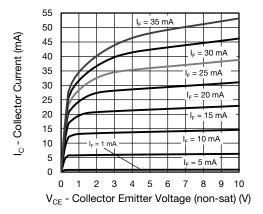


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

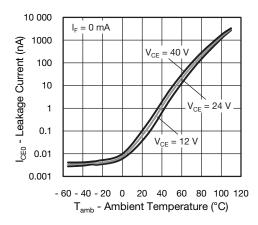


Fig. 6 - Leakage Current vs. Ambient Temperature

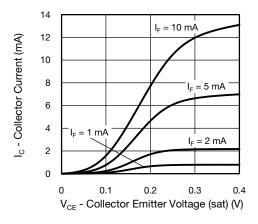


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

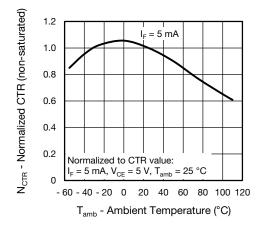


Fig. 8 - Normalized Current Transfer Ratio (non-sat) vs.
Ambient Temperature

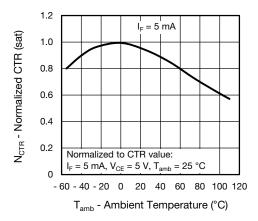


Fig. 9 - Normalized Current Transfer Ratio (sat) vs.
Ambient Temperature

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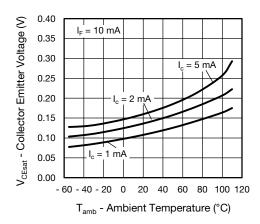


Fig. 10 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

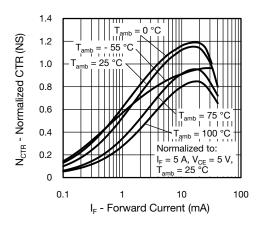


Fig. 11 - Normalized CTR (NS) vs. Forward Current

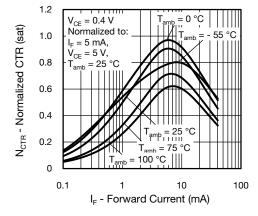


Fig. 12 - Normalized CTR (sat) vs. Forward Current

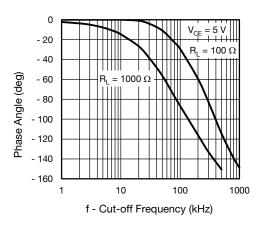


Fig. 13 - F_{CTR} vs. Phase Angle

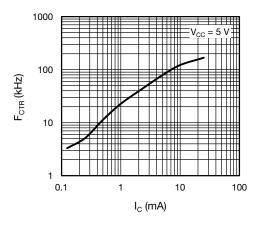


Fig. 14 - F_{CTR} vs. Collector Current

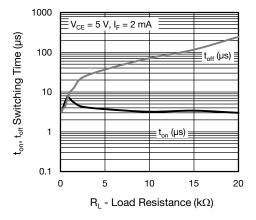


Fig. 15 - Switching Time vs. Load Resistance

1.75 ± 0.1

 0.3 ± 0.05

5.5 ± 0.1 | 12 ± 0.3

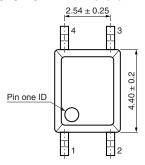
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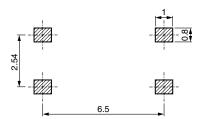
 8 ± 0.1

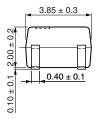


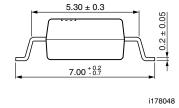
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PACKAGE DIMENSIONS in millimeters









 1.5 ± 0.1

О

0

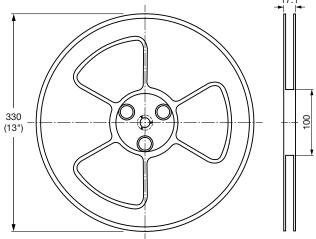
PACKAGE MARKING (example of VOM617A-3X001T)

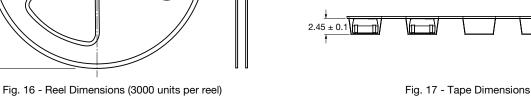


Notes

- Only option 1 is reflected in the package marking with the characters "X".
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters







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